

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S77	1	10/797876	US-PGPUB; USPAT	OR	ON	2009/05/20 17:40
S78	2	("20030218189").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/05/20 17:46
S79	162	((silicon adj1 germanium) SiGe) same ((dielectric k insulator) with high) same anneal\$3	US-PGPUB; USPAT	OR	ON	2009/06/04 08:15
S81	3	S79 and S80	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 08:16
S80	28	(US-20060086977-\$ or US- 20060071275-\$ or US- 20050250302-\$ or US- 20050242406-\$ or US- 20050199877-\$ or US- 20050181621-\$ or US- 20050099839-\$ or US- 20050139872-\$ or US- 20050064322-\$ or US- 20050045969-\$ or US- 20050070070-\$ or US- 20040169177-\$ or US- 20040227154-\$ or US- 20040157455-\$ or US- 20030010980-\$ or US- 20030098479-\$ or US- 20020014625-\$ or US- 20040099903-\$ or US- 20050130424-\$ or US- 20050079691-\$ or US- 20020115252-\$ or US- 20020050608-\$ or US- 20020048910-\$).did. or (US- 7034337-\$ or US-6423632- \$ or US-5403434-\$ or US- 6825102-\$).did. or (US- 20020174826-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2009/06/04 08:16
S84	70	S83 and S82	US-PGPUB; USPAT	OR	ON	2009/06/04 08:20
S83	47017	((silicon adj1 germanium) SiGe)	US-PGPUB; USPAT	OR	ON	2009/06/04 08:20

S82	231	anneal\$3 near5 after near5 ((dielectric k insulator) with high)	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 08:20
S85	11	("20030008521" "20060065930" "6410471" "6503861" "6501121" "6518634" "6528377" "6610548" "6638872" "7015121" "7119385").PN.	US-PGRUB; USPAT	OR	ON	2009/06/04 08:59
S86	19	anneal\$3 near5 after near5 ((dielectric k insulator) with high) near5 oxide	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:06
S87	16	interfacial same characteristics same strained	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:10
S89	342712	anneal\$3	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:45
S88	61	sige near2 surface near2 channel	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:45
S93	51	S92 and S90 and S89	US-PGRUB; USPAT	OR	ON	2009/06/04 09:46
S92	88890	((dielectric k insulator) near3 high)	US-PGRUB; USPAT	OR	ON	2009/06/04 09:46
S91	188934	((dielectric k insulator) with high)	US-PGRUB; USPAT	OR	ON	2009/06/04 09:46
S90	69	((silicon adj1 germanium) SiGe) near2 surface near2 channel	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:46
S99	39	((RAYMOND) near2 (JOE)). INV.	US-PGRUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S98	18	((SEUNGHO) near2 (OH)). INV.	US-PGRUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S97	17	((ALLEN) near2 (LEITH)). INV.	US-PGRUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S96	28	((SANJEEV) near2 (KAUSHAL)).INV.	US-PGRUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S95	175	((PRADIP) near2 (ROY)). INV.	US-PGRUB; USPAT; USOCR	OR	ON	2009/06/04 11:08

S94	44	((ANTHONY) near2 (DIP)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S101	1	S100 and S82	US-PGPUB; USPAT	OR	ON	2009/06/04 11:09
S100	272	S95 S96 S97 S98 S99 S94	US-PGPUB; USPAT	OR	ON	2009/06/04 11:09
S102	92	S100 and S89	US-PGPUB; USPAT	OR	ON	2009/06/04 11:10
L2	3077	(438/285,287,785).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/06/05 09:52
L1	616	(257/E21.091,E21.092). CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/06/05 09:52

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